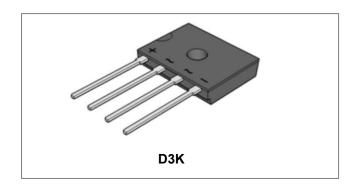






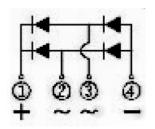
UG6KB05 THRU UG6KB100 Single-Phase 6.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- · High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

• Case: D3K, Molded plastic

Terminals: Plated leads solderable per MIL-STD-202,
 Marked 200.

Method 208

Polarity: as marked on caseMounting Position: Any

Lead Free: For RoHS / Lead Free Version

Maximum Ratings: @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	UG6K B05	UG6K B10	UG6K B20	UG6K B40	UG6K B60	UG6K B80	UG6K B100	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average Rectified Without heat sink $@T_A = 30^{\circ}C$ Output Current With heat sink $@T_A = 140^{\circ}C$	Io				3.0 6.0				Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)					А				

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 - http://www.smc-diodes.com
 sales@ smc-diodes.com







Electrical Characteristics:

Type Number	Symbol	UG6K B05	UG6K B10	UG6K B20	UG6K B40	UG6K B60	UG6K B80	UG6K B100	Units
Forward Voltage (per element) * @I _F =6.0A	V _F	1.1					V		
Peak Reverse Current * @T _A = 25°C At Rated DC Blocking Voltage * @T _A = 125°C	I _R	I _R 5.0 500			μA				
Typical Junction Capacitance(per leg) (Note 1)					21				pF

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

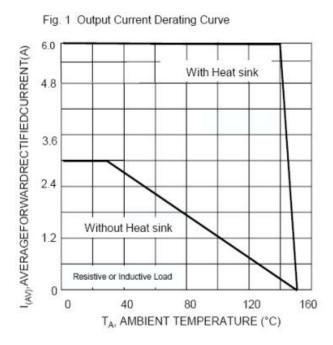
Thermal-Mechanical Specifications:

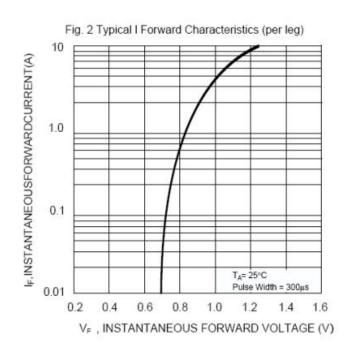
Type Number	Symbol	UG6K B05	UG6K B10	UG6K B20	UG6K B40	UG6K B60	UG6K B80	UG6K B100	Units
Typical Thermal Resistance (per leg)(Note 2) $\begin{array}{c c} R_{\theta JA} & 55 \\ R_{\theta JL} & 15 \end{array}$			°C/W						
Operating and Storage Temperature Range T _J , T _{STG} -55 to +150					°C				

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Mounted on glass epoxy PC board with 1.3mm² solder pad.

Ratings and Characteristics Curves



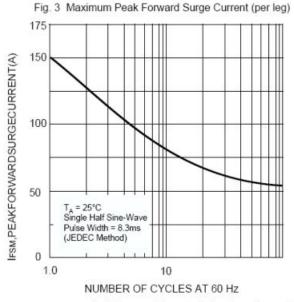


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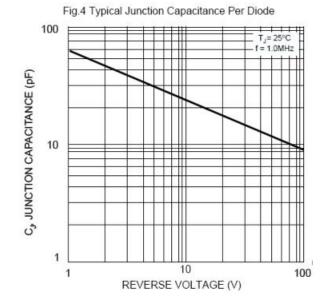
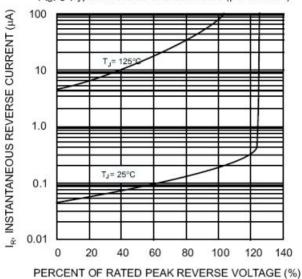


Fig. 5 T ypical Reverse Characteristics (per element)

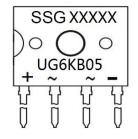


Ordering Information

Device	Package	Plating	Shipping
UG6KB05 THRU UG6KB100	D3K(Pb-Free)	Pure Sn	37pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 UG6KB05
 = Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

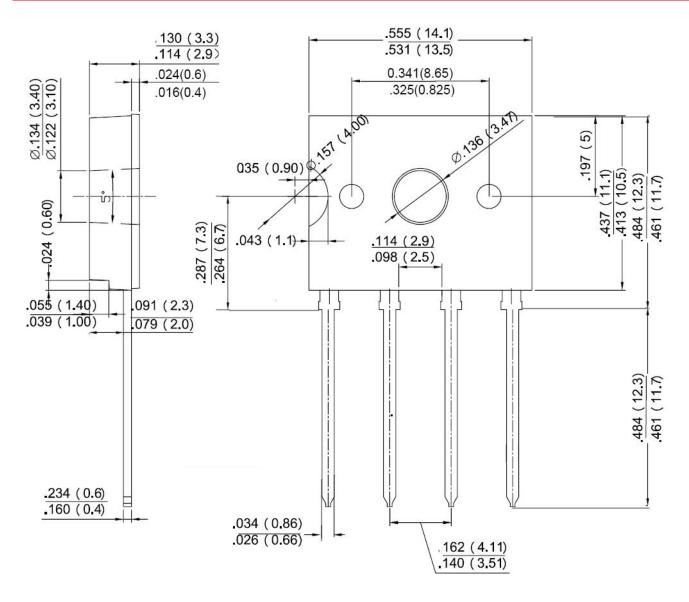
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Mechanical Dimensions D3K (Inches/Millimeters)



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UG6KB05 THRU UG6KB100

Technical Data Data Sheet N1922, Rev. A





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